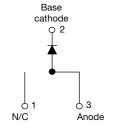


www.vishay.com

Vishay Semiconductors

# **High Performance Schottky Rectifier, 8 A**



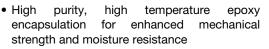


D2PAK	(TO	-263AB)
-------	-----	---------

PRODUCT SUMMARY							
I <sub>F(AV)</sub>	8 A						
V <sub>R</sub>	80 V, 100 V						
V <sub>F</sub> at I <sub>F</sub>	0.72 V						
I <sub>RM</sub> max.	7 mA at 125 °C						
T <sub>J</sub> max.	175 °C						
E <sub>AS</sub>	7.5 mJ						
Package	D2PAK (TO-263AB)						
Diode variation	Single						

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

## **DESCRIPTION**

The VS-8TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL CHARACTERISTICS VALUES									
I <sub>F(AV)</sub>	Rectangular waveform	8	Α						
V <sub>RRM</sub>	Range	80, 100	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	Α						
V <sub>F</sub>	8 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.58	V						
T <sub>J</sub>	Range	-55 to +175	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-8TQ080SPbF	VS-8TQ100SPbF	UNITS					
Maximum DC reverse voltage	V <sub>R</sub>	80	100	V					
Maximum working peak reverse voltage	$V_{RWM}$	60	100	V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 157 °C	8	А					
Maximum peak one cycle non-repetitive surge current	l=a	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	850	Α				
See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	230					
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.50 A, L = 60 mH		7.50	mJ				
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		0.50	Α				

Revision: 08-Aug-17 **1** Document Number: 94266



# VS-8TQ080SPbF, VS-8TQ100SPbF

# Vishay Semiconductors

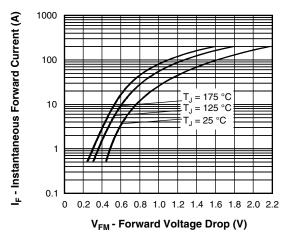
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		8 A	T <sub>.1</sub> = 25 °C	0.72				
Maximum forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	16 A	1j=25 C	0.88	V			
		8 A	T <sub>.1</sub> = 125 °C	0.58				
		16 A	1j=125 C	0.69	l			
Maximum reverse leakage current	I <sub>RM</sub> (1)	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>B</sub>	0.55	mA			
See fig. 2		T <sub>J</sub> = 125 °C	VR = nateu VR	7				
Maximum junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		500	pF			
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 m	8	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs				

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS			
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation See fig. 4	2.0	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.50	C/VV			
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Maunting toward	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device			Coop at de DODAK	8TQ(	080S			
			Case style D2PAK	8TQ <sup>-</sup>	8TQ100S			

# Vishay Semiconductors



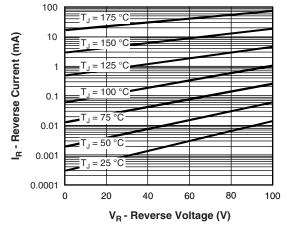


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

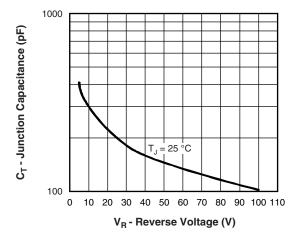


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

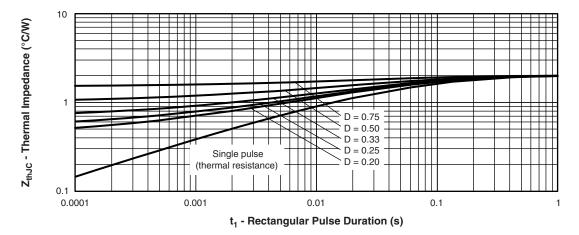


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

### www.vishay.com

# Vishay Semiconductors

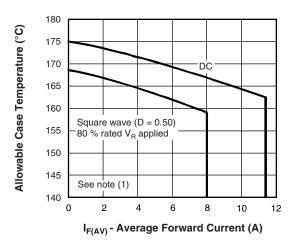


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

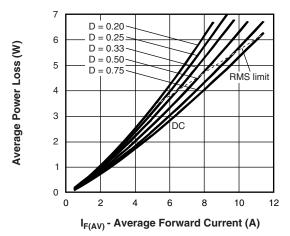


Fig. 6 - Forward Power Loss Characteristics

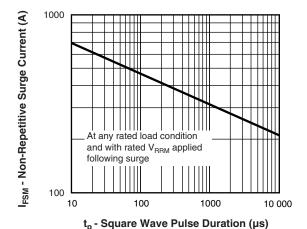


Fig. 7 - Maximum Non-Repetitive Surge Current

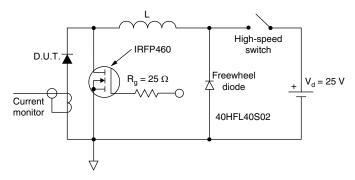


Fig. 8 - Unclamped Inductive Test Circuit

## Note

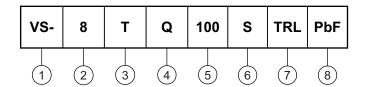
 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

# VS-8TQ080SPbF, VS-8TQ100SPbF

Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Current rating (8 A)

**3** - Circuit configuration: T = TO-220

4 - Schottky "Q" series

080 = 80 V 100 = 100 V

6 - S = D<sup>2</sup>PAK

7 - • None = tube (50 pieces)

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95046</u>						
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					
SPICE models	www.vishay.com/doc?96227					



# Vishay Semiconductors

## D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		HES NOTES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

# **Legal Disclaimer Notice**



Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.